2SC5960



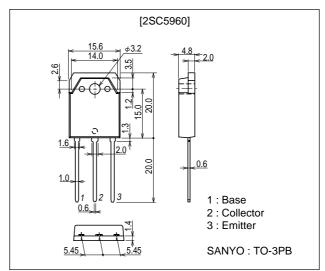
# **Switching Regulator Applications**

### **Features**

- · High breakdown voltage and high reliability.
- · High-speed switching.
- · Wide ASO.
- · Adoption of MBIT process.

### **Package Dimensions**

unit : mm 2022A



# **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		7	Α
Collector Current (Pulse)	ICP	PW≤300μs, Duty Cycle≤10%	14	Α
Base Current	IB		3	Α
Collector Dissipation	D-		2.5	W
	PC	Tc=25°C	60	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =400V, I <sub>E</sub> =0			10	μΑ
Emitter Cutoff Current	IEBO	VEB=5V, IC=0			10	μА

Continued on next page.

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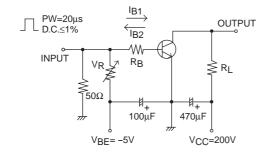
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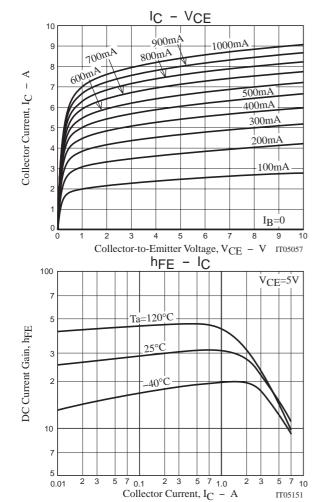
Parameter	r Symbol Conditions	Conditions	Ratings			Unit
raidifietei		min	typ	max	Offic	
	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =0.8A	20*		50*	
DC Current Gain	hFE2	V <sub>CE</sub> =5V, I <sub>C</sub> =4A	10			
	hFE3	VCE=5V, IC=1mA	10			
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =4A, I <sub>B</sub> =0.8A			0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =4A, I <sub>B</sub> =0.8A			1.5	V
Gain-Bandwidth Product	fT	VCE=10V, IC=0.8A		15		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		50		pF
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Turn-On Time	ton	I <sub>C</sub> =5A, I <sub>B1</sub> =1A, I <sub>B2</sub> =-2A, R <sub>L</sub> =40Ω, V <sub>CC</sub> =200V			0.5	μs
Storage Time	t <sub>stg</sub>	I <sub>C</sub> =5A, I <sub>B1</sub> =1A, I <sub>B2</sub> =-2A, R <sub>L</sub> =40Ω, V <sub>CC</sub> =200V			2.5	μs
Fall Time	tf	I <sub>C</sub> =5A, I <sub>B1</sub> =1A, I <sub>B2</sub> =-2A, R <sub>L</sub> =40Ω, V <sub>CC</sub> =200V			0.3	μs

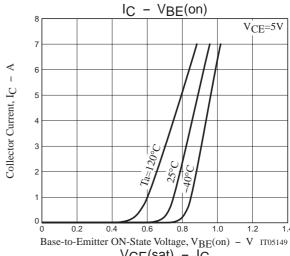
\*: The hFE1 of the 2SC5960 is classified as follows.

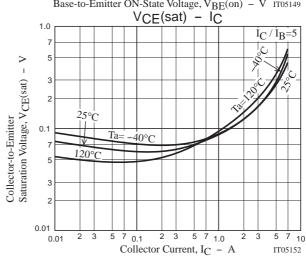
Rank	М	N		
hFE	20 to 40	30 to 50		

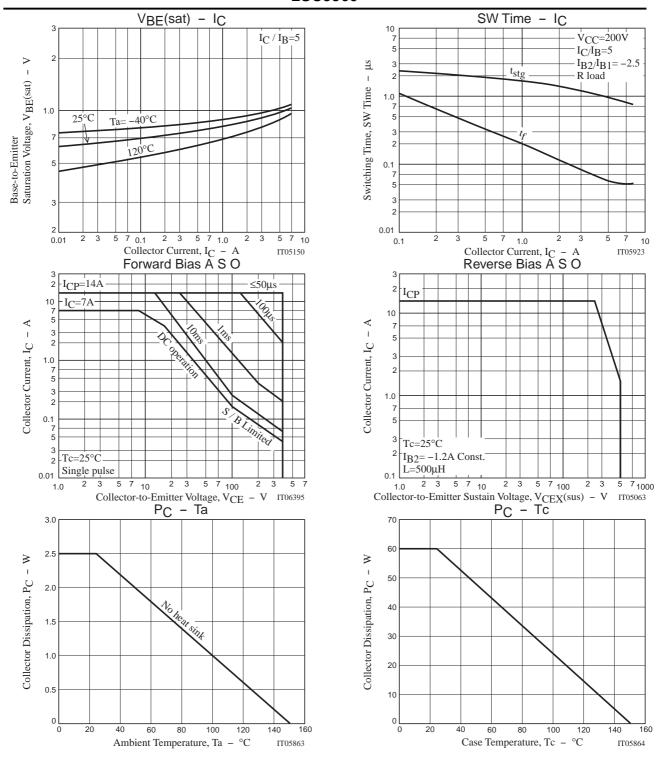
## **Switching Time Test Circuit**











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